

Principles of Electronics Design 521431A

Exam 18/12/2009

—

1. Draw on a same scale the output and input voltages of the circuit of Fig. 1 in case when current $I = 1 \text{ mA}$. The diode is a normal small-signal diode, capacitances are very large, $R_s = 100 \Omega$ and v_s is an ac-signal with the amplitude of 10 mV and the frequency is such that capacitances can be considered as short-circuits. How does the output change if I is changed to $100 \mu\text{A}$? Can you imagine any use for this circuit?

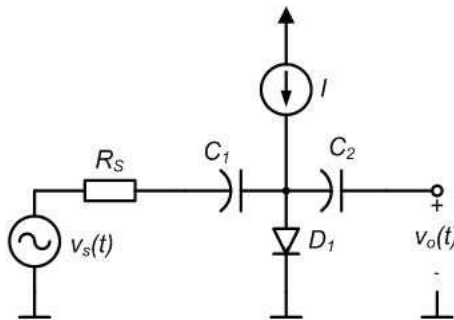


Figure 1: Figure for question 1.

2. An npn-transistor ($\beta \gg$) amplifier stage is shown in Figure 2.
 - (a) How is it called?
 - (b) Dimension the dc-operating point of the amplifier stage so that voltage drop over collector resistance R_C is $V_{CC}/3$ and voltage drop between collector and emitter is $V_{CE} = V_{CC}/3$. The emitter current of the transistor stage should be $I_E = 1 \text{ mA}$ and input impedance between $1 \text{ k}\Omega - 10 \text{ k}\Omega$.
 - (c) Dimension the open loop ($R_S = 0 \Omega$ and $R_L \gg$) voltage gain $v_{out}/v_{in} = -10V/V$.
 - (d) What are the input and output impedance values of the transistor stage?

Capacitance values (C_B , C_C and C_E) are very large.

3. In the op amp circuit of Fig. 3 $R_1 = R_3 = 1 \text{ k}\Omega$ and $R_2 = R_4 = 100 \text{ k}\Omega$
 - (a) What is the amplification for input signal and the amplitude of the output signal if $u_{in} = 0.01 \sin(2\pi 1 \text{ kHz} \cdot t) \text{ V}$? (2p)
 - (b) What is the dc-level at the output? (1p)
 - (c) What is the input impedance of the circuit? (1p)
 - (d) You want to limit the bandwidth of the circuit to about 16 kHz so that the signal u_{in} at 1 kHz and lower frequencies are not attenuated. How do you modify the circuit? (1p)
 - (e) What is the transfer function $\frac{u_{out}}{u_{in}}$ of the circuit after the change you made? Please provide a symbolic solution in the s-plane. (1p)

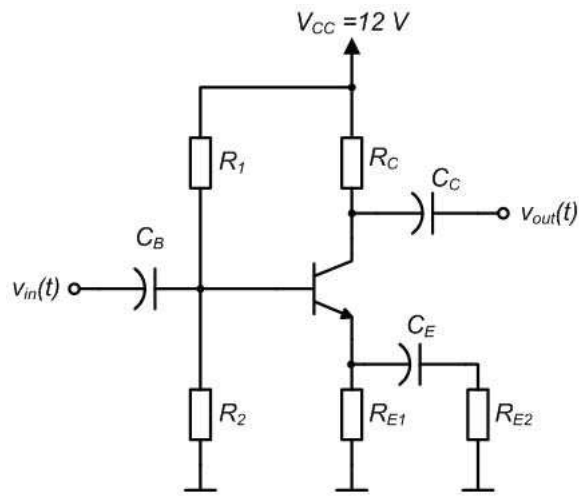


Figure 2: Figure for question 2.

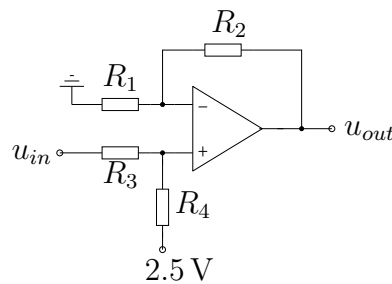


Figure 3: Figure for question 3.

4. Find the input and output impedance of the MOSFET amplifier shown in figure 4? Find the value of R_1 and W/L ratio so that the gain $u_L/u_{src} > 10$. Transistor parameters: $\mu_n C_{ox} = 25 \mu\text{A}/\text{V}^2$, $\lambda = 0$ and $U_t = 2\text{V}$. Capacitors C_1 , C_2 and C_3 are large coupling capacitors. (6p)

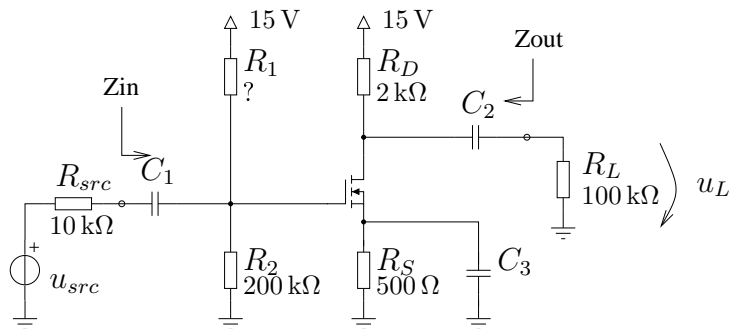


Figure 4: Figure for question 4.

$$i_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (u_{GS} - U_t)^2 (1 + \lambda \cdot u_{DS})$$

$$g_m = \left. \frac{\partial i_D}{\partial u_{GS}} \right|_{u_{GS}=U_{GS}} = \mu_n C_{ox} \frac{W}{L} (U_{GS} - U_t)$$